

### 1. General description

Planar passivated SCR with sensitive gate in a SOT223 surface mountable plastic package. This SCR is designed to be interfaced directly to microcontrollers, logic integrated circuits and other low power gate trigger circuits.

### 2. Features and benefits

- Sensitive gate
- · Planar passivated for voltage ruggedness and reliability
- Direct triggering from low power drivers and logic ICs
- Surface mountable package

### 3. Applications

- Ground Fault Circuit Interrupters (GFCI)
- · General purpose switching and phase control
- Ignition circuits, CDI for 2- and 3-wheelers
- Motor control e.g. small kitchen appliances

### 4. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>DRM</sub>	repetitive peak off- state voltage		-	-	1000	V
V <sub>RRM</sub>	repetitive peak reverse voltage		-	-	1000	V
I <sub>T(AV)</sub>	average on-state current	half sine wave; $T_{sp} \le 100 \text{ °C}$	-	-	0.8	A
I <sub>T(RMS)</sub>	RMS on-state current	half sine wave; T <sub>sp</sub> ≤ 100 °C; <u>Fig. 1;</u> <u>Fig. 2; Fig. 3</u>	-	-	1.1	A
I <sub>TSM</sub>	non-repetitive peak on- state current	half sine wave; T <sub>j(init)</sub> = 25 °C; t <sub>p</sub> = 10 ms; <u>Fig. 4</u> ; <u>Fig. 5</u>	-	-	11	A
Static chara	acteristics					
I <sub>GT</sub>	gate trigger current	$V_D = 12 \text{ V}; \text{ I}_T = 10 \text{ mA}; \text{ T}_j = 25 \text{ °C};$ Fig. 7	15	-	50	μA

#### 5. Pinning information

-	-	

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	К	cathode	4	А-Ӈ-К
2	А	anode		G sym037
3	G	gate		Symosr
4	А	mb; connected to anode	☐1 ☐2 <b>☐</b> 3 SC-73 (SOT223)	

# 6. Ordering information

Table 3. Ordering information						
Type number	Package	age				
	Name	Description	Version			
NCR100W-12L	SC-73	plastic surface-mounted package with increased heatsink; 4 leads	SOT223			

### 7. Marking

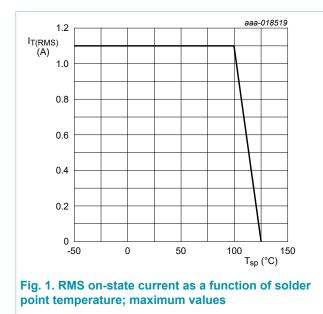
Table 4. Marking codes					
	Type number	Marking code			
	NCR100W-12L	10012L			

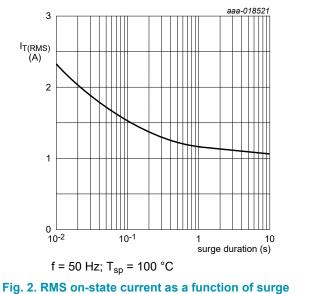
### 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>DRM</sub>	repetitive peak off-state voltage		-	1000	V
V <sub>RRM</sub>	repetitive peak reverse voltage		-	1000	V
I <sub>T(AV)</sub>	average on-state current	half sine wave; T <sub>sp</sub> ≤ 100 °C	-	0.8	А
I <sub>T(RMS)</sub>	RMS on-state current	half sine wave; $T_{sp} \le 100 \text{ °C}$ ; <u>Fig. 1</u> ; Fig. 2; Fig. 3	-	1.1	A
I <sub>TSM</sub>	non-repetitive peak on- state current	half sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 10 ms; Fig. 4; Fig. 5	-	11	A
		half sine wave; T <sub>j(init)</sub> = 25 °C; t <sub>p</sub> = 8.3 ms	-	12.1	А
l <sup>2</sup> t	I <sup>2</sup> t for fusing	t <sub>p</sub> = 10 ms; SIN	-	0.605	A²s
dl <sub>T</sub> /dt	rate of rise of on-state current	I <sub>G</sub> = 0.1 mA	-	50	A/µs
I <sub>GM</sub>	peak gate current		-	1	А
V <sub>RGM</sub>	peak reverse gate voltage		-	5	V
P <sub>GM</sub>	peak gate power		-	2	W
P <sub>G(AV)</sub>	average gate power	over any 20 ms period	-	0.1	W
T <sub>stg</sub>	storage temperature		-40	150	°C
Tj	junction temperature		-	125	°C

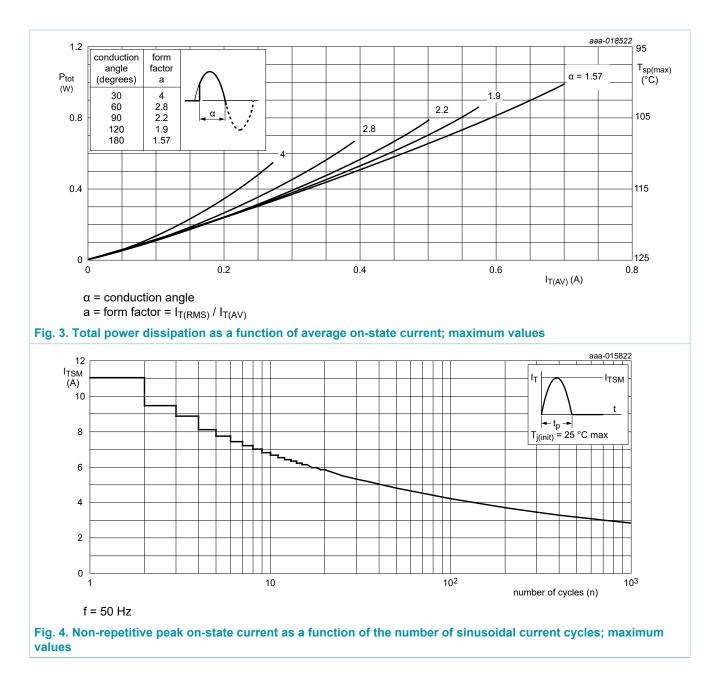




duration; maximum values

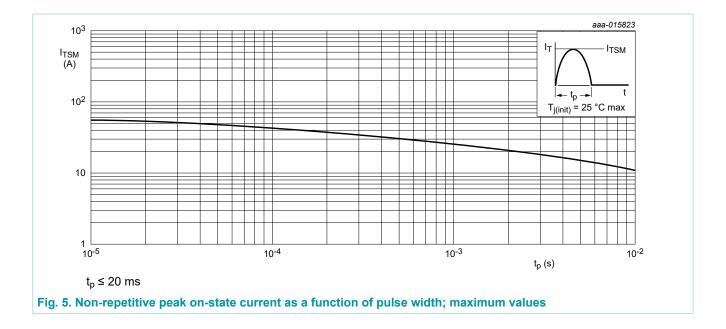
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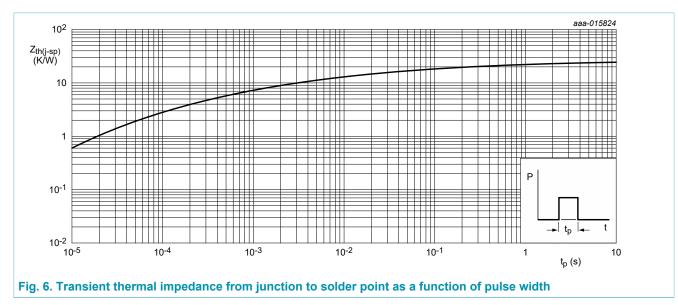
# NCR100W-12L

SCR



#### 9. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point	half cycle; <u>Fig. 6</u>	-	-	25	K/W
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient free air	printed circuit board mounted; minimum footprint; in free air	-	130	-	K/W

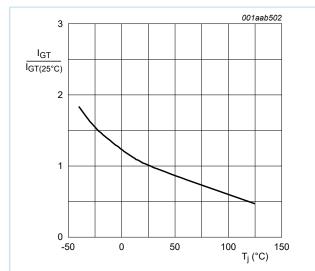


### **10. Characteristics**

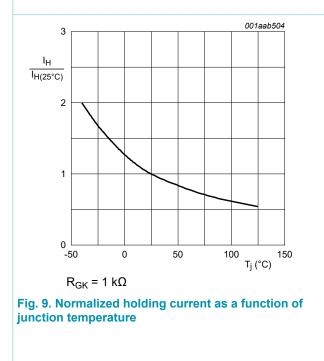
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
I <sub>GT</sub>	gate trigger current	V <sub>D</sub> = 12 V; I <sub>T</sub> = 10 mA; T <sub>j</sub> = 25 °C; Fig. 7	15	-	50	μA
IL	latching current	$V_D$ = 12 V; I <sub>G</sub> = 0.5 mA; T <sub>j</sub> = 25 °C; R <sub>GK(ext)</sub> = 1 kΩ; Fig. 8	-	-	6	mA
I <sub>H</sub>	holding current	$V_D$ = 12 V; T <sub>j</sub> = 25 °C; R <sub>GK(ext)</sub> = 1 kΩ; Fig. 9	-	-	3	mA
V <sub>T</sub>	on-state voltage	I <sub>T</sub> = 1.2 A; T <sub>j</sub> = 25 °C; <u>Fig. 10</u>	-	1.25	1.7	V
V <sub>GT</sub>	gate trigger voltage	V <sub>D</sub> = 12 V; I <sub>T</sub> = 10 mA; T <sub>j</sub> = 25 °C; <u>Fig. 11</u>	-	0.5	0.8	V
		V <sub>D</sub> = 1000 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 125 °C; Fig. 11	0.3	0.5	-	V
I <sub>D</sub>	off-state current	$V_D$ = 1000 V; $R_{GK(ext)}$ = 1 k $\Omega$ ; T <sub>j</sub> = 125 °C	-	0.05	1	mA
I <sub>R</sub>	reverse current	$V_R$ = 1000 V; T <sub>j</sub> = 125 °C; R <sub>GK(ext)</sub> = 1 kΩ	-	0.05	1	mA
Dynamic ch	naracteristics	· · · ·				
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$V_{DM}$ = 670 V; T <sub>j</sub> = 125 °C; R <sub>GK</sub> = 1 kΩ; exponential waveform; (V <sub>DM</sub> = 67% of V <sub>DRM</sub> )	100	-	-	V/µs
t <sub>gt</sub>	gate-controlled turn-on time	$I_{TM}$ = 2 A; V <sub>D</sub> = 1000 V; I <sub>G</sub> = 10 mA; dI <sub>G</sub> /dt = 0.1 A/µs; T <sub>j</sub> = 25 °C	-	2	-	μs
t <sub>q</sub>	commutated turn-off time	$V_{DM}$ = 670 V; T <sub>j</sub> = 125 °C; I <sub>TM</sub> = 1.6 A; $V_R$ = 35 V; (dI <sub>T</sub> /dt) <sub>M</sub> = 30 A/µs; dV <sub>D</sub> / dt = 2 V/µs; R <sub>GK(ext)</sub> = 1 kΩ; (V <sub>DM</sub> = 67% of V <sub>DRM</sub> )	-	100	-	μs

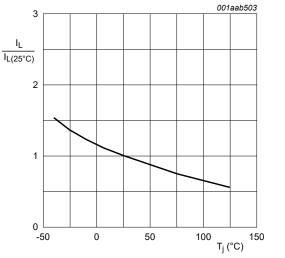
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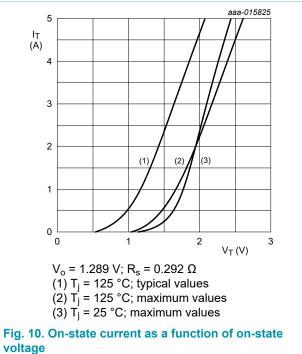
# Fig. 7. Normalized gate trigger current as a function of junction temperature





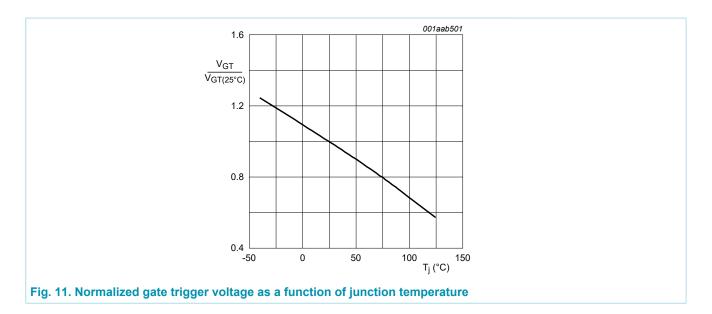




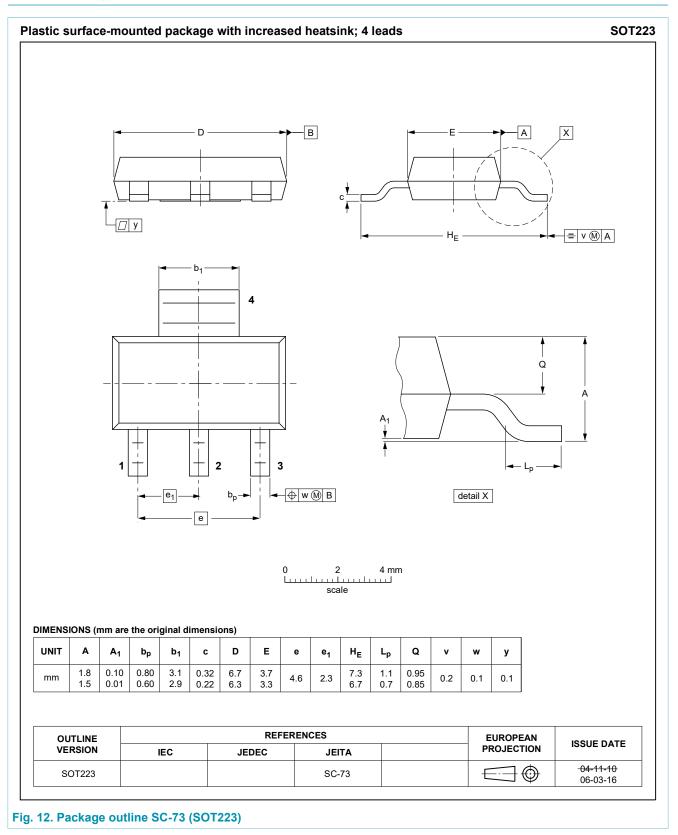


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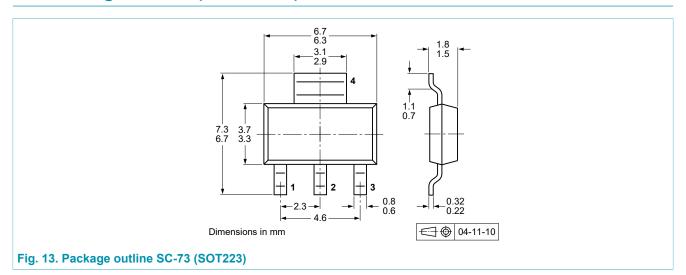
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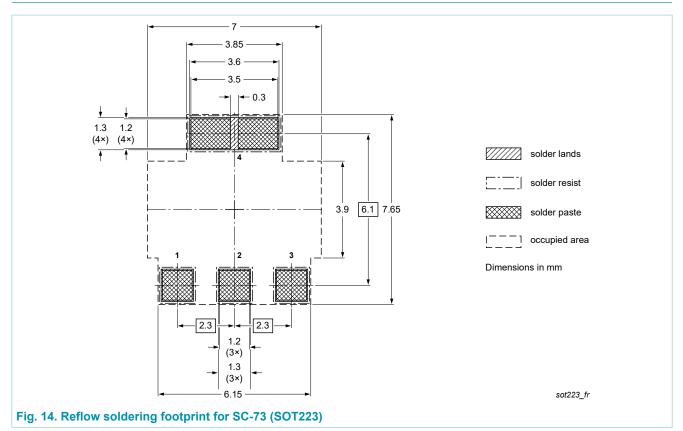
### 11. Package outline



#### 12. Package outline (minimized)

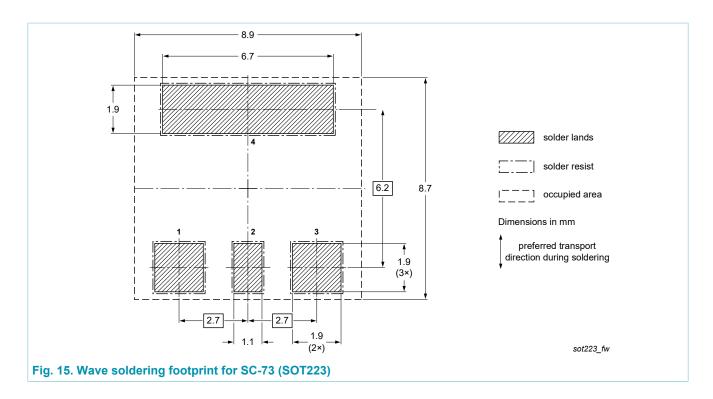


# 13. Soldering



# NCR100W-12L

SCR



## NCR100W-12L

#### SCR

# 14. Legal information

#### Data sheet status

Document status [1][2]	Product status [ <u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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